Raytheon

DECLARATION FOR PATENT APPLICATION AND POWER OF ATTORNEY

	Page 1 of 2
OIPE	Attorney Docket No. 03W089
	■ Original
no)	☐ Continuation
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Á Ä	☐ Continuation-
198	in-part
PANEMARK	☐ Supplemental

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name.

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled

Low Power Current Input Delta-Sigma ADC Using Injection FET Reference

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the specification of wh	ich						
	was fil		_as Application No. <u>10/769,111</u> ended on or (b) [supplem				
		iewed and understand t endment referred to abo	he contents of the above identified ove.	specification, includ	ing the		
I acknowledge the duty to disclose to the United States Patent and Trademark Office all information known to me to be material to patentability as defined in Title 37, Code of Federal Regulations, §1.56.							
I hereby claim foreign priority benefits under Title 35, United States Code, §119 of any foreign application(s) for patent or inventor's certificate listed below and have also identified below any foreign application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed:							
Prior Foreign Application	on(s)			Priority Claimed □ Yes □ No			
Number	_	Country	Day/Month/Year Filed				
I hereby claim the benefit under Title 35, United States Code, §120 of any United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code §112, I acknowledge the duty to disclose to the United States Patent and Trademark Office all information known to me to be material to patentability as defined in Title 37, Code of Federal Regulations, §1.56 which became available between the filing date of the prior application and the national or PCT international filing date of this application:							
Application Serial N	lo.	Filing Date	Status				
			(patented, pending, abai	ndoned)			

Raytheon Company Intellectual Property & Licensing, Loc: EO/E04/N119

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DECLARATION and POWER OF ATTORNEY
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Attorney Docket No. 03W089*

re: Low Power Current Input Delta-Sigma ADC Using Injection FET Reference

I hereby appoint the following attorneys, or agent and attorneys, to prosecute this application and to transact all business in the Patent and Trademark Office connected therewith:

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I HEREBY DECLARE THAT ALL STATEMENTS MADE HEREIN OF MY OWN KNOWLEDGE ARE TRUE AND THAT ALL STATEMENTS MADE ON INFORMATION AND BELIEF ARE BELIEVED TO BE TRUE; AND FURTHER THAT THESE STATEMENTS WERE MADE WITH THE KNOWLEDGE THAT WILLFUL FALSE STATEMENTS AND THE LIKE SO MADE ARE PUNISHABLE BY FINE OR IMPRISONMENT, OR BOTH, UNDER SECTION 1001 OF TITLE 18 OF THE UNITED STATES CODE AND THAT SUCH WILLFUL FALSE STATEMENTS MAY JEOPARDIZE THE VALIDITY OF THE APPLICATION OR ANY PATENT ISSUED THEREON.

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*Government contract related N66001-02-C-8078							

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